NSN 5962-00-325-5911



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-00-325-5911 **Body Length:** Between 0.370 inches and 0.395 inches **Body Width:** Between 0.240 inches and 0.260 inches **Body Height:** Between 0.050 inches and 0.085 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/enable and expandable and w/buffered output and wire-or outputs and bipolar and programmable and programmed and w/decoded output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 8 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 25.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:**

82577-932085 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 flat leads

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Voc. domil/mli

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